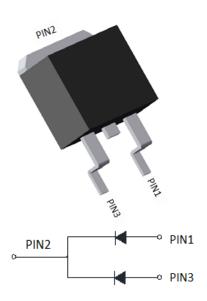


Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-263

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102
• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

=maximum Natings (Ta 20 0 offices office office)					
PARAMETER	SYMBOL	UNIT	MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Device marking code			MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Repetitive Peak Reverse Voltage	V_{RRM}	V	100	150	200
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25°C	Io	Α	10		
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25℃	I _{FSM}	Α	100		
Current Squared Time @1ms≤t<8.3ms Tj=25℃,	l ² t	A ² s	41		
Storage Temperature	Tstg	$^{\circ}$	-55 ~ + 175		
Junction Temperature	Tj	$^{\circ}$	-55 ~ +175		

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
Maximum instantaneous forward voltage drop per diode	V_{FM}	٧	I _{FM} =5.0A	0.85	0.9	0.95
Maximum DC reverse current at	I _{RRM1}		V _{RM} =V _{RRM} Ta=25°C	0.1		
rated DC blocking voltage per diode	I _{RRM2}	mA	V _{RM} =V _{RRM} Ta=125℃	20		

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

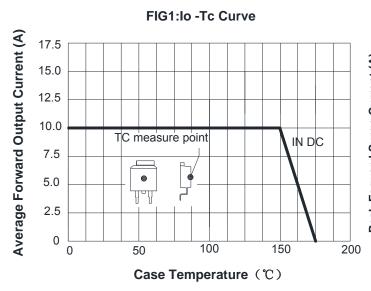
					•		
	P/	ARAMETER	SYMBOL	UNIT	MBRB10100CTS	MBRB10150CTS	MBRB10200CTS
	Thermal Resistance	Between junction and case	$R_{\theta J\text{-}C}$	%/W		2.0	



■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRB10100CTS THRU MBRB10200CTS	Approximate 1.43	50	2000	8000	Tube
MBRB10100CTS THRU MBRB10200CTS	Approximate 1.43	1000	2000	10000	Reel

■Characteristics (Typical)



140

120

100

80

80

Half Sine-Wave JEDEC Method

20

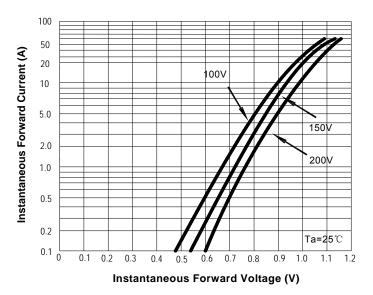
Number of Cycles

FIG.4: Instantaneous Reverse Characteristics

2

FIG2:Surge Forward Current Capability

FIG3: Forward Voltage



100

Tj=125°C

1.0

Tj=25°C

Tj=25°C

Tj=25°C

Tj=25°C

Tj=25°C

Tj=25°C

Tj=25°C

Tj=25°C

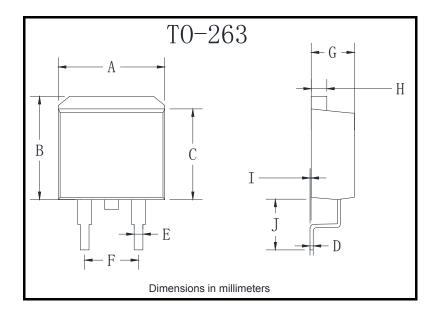
Tj=25°C

2/4

100



■Outline Dimensions



TO-263						
Dim	Min	Max				
Α	9.5	11.5				
В	9.7	10.5				
С	8.4	9.0				
D	0.28	0.64				
Е	0.68	0.94				
F	4.55	5.6				
G	4.04	5.10				
Н	1.14	1.4				
I	0	0.2				
J	4.9	6.05				



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